

SANYO Semiconductors DATA SHEET

2SA1575 / 2SC4080 — High-Frequency Amplifier, Wide-Band Amplifier Applications

Features

- · High fT.
- · High breakdown voltage.
- Small reverse transfer capacitance and excellent high-frequency characteristic.
- · Adoption of FBET process.

Specifications (): 2SA1575

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)200	V
Collector-to-Emitter Voltage	VCEO		(-)200	V
Emitter-to-Base Voltage	VEBO		(-)4	V
Collector Current	Ic		(-)100	mA
Collector Current (Pulse)	ICP		(-)200	mA
Collector Dissipation	D-		500	mW
	PC	Mounted on a ceramic board (250mm²X0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)150V, I _E =0A			(-)0.1	μΑ
Emitter Cutoff Current	IEBO	VEB=(-)2V, IC=0A			(-)1.0	μΑ
DC Current Gain	hFE1	V _{CE} =(-)10V, I _C =(-)10mA	40*		320*	
Do Current Gain	hFE2	V _{CE} =(-)10V, I _C =(-)60mA	20			
Gain-Bandwidth Product	fŢ	VCE=(-)30V, IC=(-)30mA		400		MHz
Output Capacitance	Cob	V _{CB} =(-)30V, f=1MHz		(2.3)1.8		pF
Reverse Transfer Capacitance	Cre	VCB=(-)30V, f=1MHz		(1.7)1.4		pF

Marking: 2SA1575: AF / 2SC4080: CI

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 $\mbox{\ensuremath{^{*}}}$: The 2SA1575 / 2SC4080 are classified by 10mA hFE as follows :

Rank	С	D	Е	F
hFE	40 to 80	60 to 120	100 to 200	160 to 320

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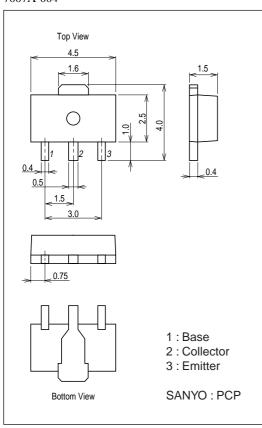
2SA1575 / 2SC4080

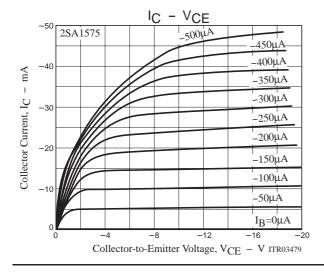
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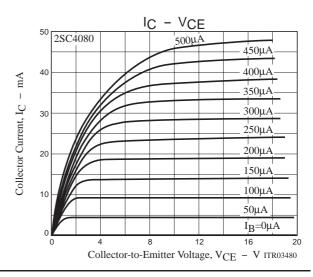
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=(-)20mA, IB=(-)2mA			(-)1.0	V
Base-to-Emitterr Saturation Voltage	V _{BE} (sat)	I _C =(-)20mA, I _B =(-)2mA			(-)1.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=(-)10μA, IE=0A	(-)200			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=(-)1mA, RBE=∞	(-)200			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)100μA, I _C =0A	(-)4			V

Package Dimensions

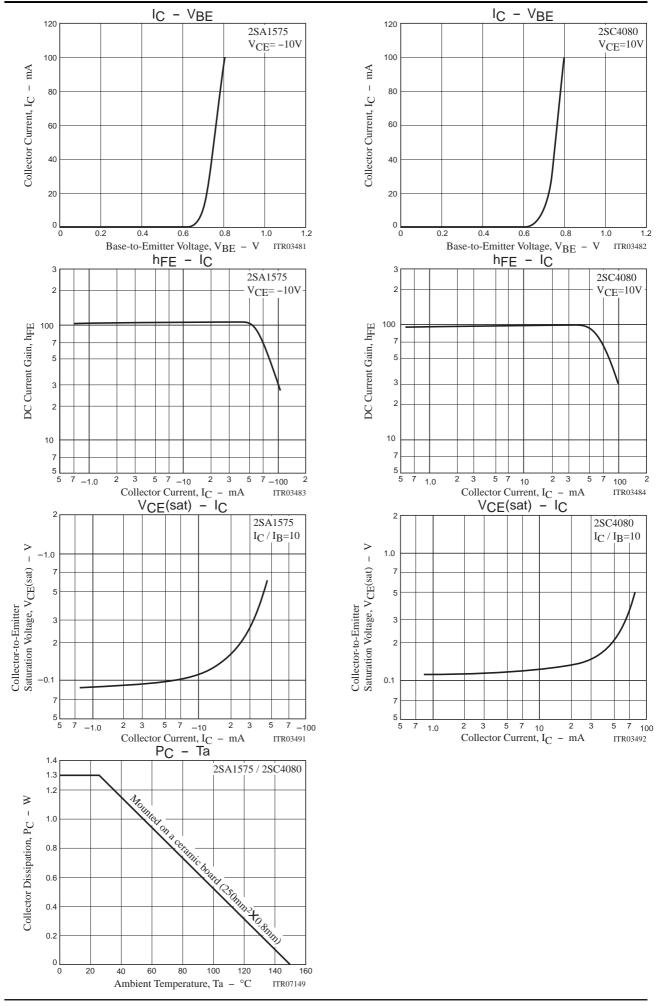
unit : mm (typ) 7007A-004







2SA1575 / 2SC4080



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